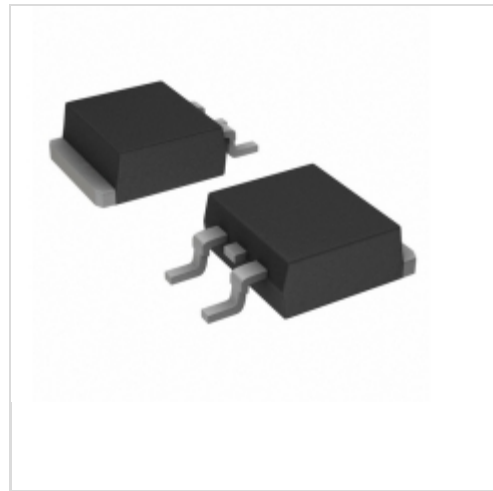


UGB8DT-E3/81



Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 200V 8A TO263AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

[UGB8DT-E3/81.pdf](#)

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Out Stock

0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

part#UGB8DT-E3/81 is available, see description of UGB8DT-E3/81 as below .

use the request quote form to request UGB8DT-E3/81 price and lead time.

Buy Electronic Components at zeanoit.com .we are an independent distributor of electronic components with extensive inventory in stock.

The price and lead time for UGB8DT-E3/81 depending on the quantity required, availability and warehouse location.Contact us today and our sales team will send you quotation soon.

Email: sales@zeanoit.com

Shopping Process

1

Confirm the product

2

submit the order

3

payment

4

wait for delivery

5

receive the goods

Specifications

Voltage - Forward (Vf) (Max) @ If:	1V @ 8A
Voltage - DC Reverse (Vr) (Max):	200V
Supplier Device Package:	TO-263AB
Speed:	Fast Recovery = 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	30ns
Packaging:	Tape & Reel (TR)
Package / Case:	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Operating Temperature - Junction:	-55°C ~ 150°C
Mounting Type:	Surface Mount
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	10µA @ 200V
Current - Average Rectified (Io):	8A
Capacitance @ Vr, F:	-

Related products



UGB8CTHE3/45

DIODE GEN PURP 150V 8A TO263AB

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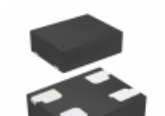
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DIODE GEN PURP 150V 8A TO263AB

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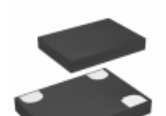


SIT1602BI-13-28S-66.666600D

-40 TO 85C, 2520, 50PPM, 2.8V, 6

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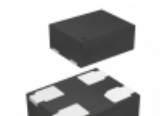


SIT1602BI-83-30S-14.000000T

-40 TO 85C, 7050, 50PPM, 3.0V, 1

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SIT1602BI-71-30S-33.000000D

-40 TO 85C, 2016, 20PPM, 3.0V, 3

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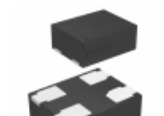


SIT8008AIA23-33E-16.000000E

OSC MEMS 16.0000MHZ LVCMOS SMD

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SIT1602BI-71-25N-6.000000E

-40 TO 85C, 2016, 20PPM, 2.5V, 6

[SITIME](#)

[RFQ](#)



SIT1602BC-31-18S-33.333300T

-20 TO 70C, 5032, 20PPM, 1.8V, 3

[SITIME](#)

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SIT1602BC-81-30N-33.333300T

-20 TO 70C, 7050, 20PPM, 3.0V, 3

[SITIME](#)

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SIT1602BC-31-30E-4.000000Y

-20 TO 70C, 5032, 20PPM, 3.0V, 4

[SITIME](#)

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SIT1602BI-32-33E-24.576000T

OSC MEMS 24.5760MHZ LVCMOS SMD

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CB3-3C-14M7456

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